NSN 5962-01-367-1272

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View Online at https://aerobasegroup.com/nsn/5962-01-367-1272

Body Length:

Between 1.480 inches and 1.500 inches

Body Width:

Between 0.600 inches and 0.620 inches

Body Height:

Between 0.212 inches and 0.242 inches

Maximum Power Dissipation Rating:

350.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Eo lorops

Features Provided:

Monolithic and ultraviolet erasable and programmed and electrostatic sensitive

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Input Circuit Pattern:

24 input

Criticality Code Justification:

Feat

Case Outline Source And Designator:

D-10 mil-m-38510

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, programmed

Voltage Rating And Type Per Characteristic:

-0.6 volts total supply and 6.2 volts total supply

Time Rating Per Chacteristic:

250.00 nanoseconds access

Memory Device Type:

Eprom

Special Features:

Esd; altered item programmed using 67268/5962-8764803xx using file 13691034.Jed

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type And Quantity:

28 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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